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一、动力学及过热电子

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CdSe/CdZnSe 多量子阱的激子 复合性质的研究 *

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薄膜电致发光器件中电子输运的瞬态过程 *

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主链含电子传输型基团的 可溶性 PPV 发光特性研究

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以 ZnO 为电子传输层 PPV 的发光*

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8-羟基喹啉铝发光特性及老化的研究

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聚合物 PVK 掺杂 1,3-二(2-苯并恶唑)- -苯(OXA)的光致发光*

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光激励发光的并行模型*

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研究快报

可溶性 PPV 衍生物电致发光性质的研究*

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光激励发光在 X 射线检测技术中的应用*

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$\text{Eu}^{2+}:\text{BaFCl}$ 光激励发光衰减的研究*

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基于 ZBLAN:Pr, Yb 玻璃上转换发光的三维立体显示*

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Er^{3+} 和 Yb^{3+} 共掺杂氟氧化物微晶玻璃中的 交叉弛豫对发光的影响*

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摘要 研究了在氟氧化物微晶玻璃中 Yb^{3+} 和 Er^{3+} 之间的能量交叉弛豫对发光和上转换的影响。结果显示, 交叉弛豫对光谱形状和发光强度都有明显的影响。

关键词: 稀土, 交叉弛豫, 氟氧化物微晶玻璃, 发光

Organic Light Emitting Diode Using Inorganic Material as Electron Transport Layer

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ADVANCES IN ELECTRONIC AND INFORMATION ENGINEERING

THREE-DIMENSION DISPLAY BASED ON UPCONVERSION OF ZBLAN:Pr,Yb GLASS

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Electrochemical Society Proceedings Volume 98-24

PROBLEMS IN BLUE ELECTROLUMINESCENCE

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Abstract:

In the frame of layered optimization and based on the previous analysis, we investigated factors influencing the occurrence and brightness of blue emission such as intervalley scattering, ionization of excited centers, serial structure of layered optimization, role of CdS in providing primary electrons and influence of sulfur vacancies.

Monochrome electroluminescence(EL) flat panel display was produced in 1983 by Sharp Corporation. Now it is widely used in different techniques. But for information display it is required to have color display, especially full color display. The problem is focused on finding blue electroluminescent materials with sufficient brightness, for example, more than 12 nit, which is the lowest requirement for full color display. Therefore, in recent years many researchers are devoting themselves to this endeavor along different directions. Many works

The Electron Transfer Process in Electron Capture Materials

SPIE Vol. 3562

ZHAO Hui¹ WANG Yongsheng XU Zheng CHENG Zhengwei XU Xurong

SPIE Vol. 3562

The Difference Between Two kinds of Electron Traps in BaFCl:Eu²⁺

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《半导体器件与器件技术》英文版

Charged Centers in ZnS-Type Thin Film Electroluminescent Devices*

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Czechoslovak Journal of physics, vol. 48(1998), NO. 9
此为抽印本, 因无赠刊, 只作用抽印本.

1998

EFFECTS OF EXCITATION AND BLEACHING OF ULTRAVIOLET DURING PHOTOSTIMULATED LUMINESCENCE OF BaFCl:Eu²⁺ PHOSPHORS*)

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JOURNAL OF THE CHINESE RARE EARTH SOCIETY

1998 年 11 月
Nov. 1998

X 射线影象存储材料 BaFCl:Eu²⁺ 的热释发光性质*

王永生 赵辉 徐征 孙力 徐叙琰

Electron Acceleration Process in ZnS-Type Thin Film Electroluminescence Devices *

ZHAO Hui(赵辉), WANG Yong-sheng(王永生), XU Zheng(徐征), XU Xu-rong(徐叙璐)
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Semiconductor Science and Technology

NOTES

Influence of the electric field on carriers recombination zone in bilayer organic electroluminescent device

YANG Shengyi, WANG Zhenjia, XU Zheng, CHEN Xiaohong, HOU Yanbing & XU Xurong

Journal of Applied Polymer Science Vol 74

Synthesis, Photo-, and Electroluminescent Properties of the Soluble Poly[(2,5-diphenylene-1,3,4-oxadiazole)-4,4'-vinylene]

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LETTERS

Interchain charge-transfer states in poly[(2,5-diphenylene-1,3,4-oxadiazole)-4,4'-vinylene] (O-PPV) oligomer

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Xinkang Zhang ^{b,*}

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INTERVALLEY SCATTERING AND BLUE ELECTROLUMINESCENCE

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Semicond. Sci. Technol. 14 (1999) 1-4. Printed in the UK

PII: S0268-1242(99)00045-0

Influence of charged centres on transport properties of thin film electroluminescent devices

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Sunrise Setting
Marked Proof
SST/100045/PAP
17360...

AUTHOR PROOF

MECHANISM OF PHOTOSTIMULATED LUMINESCENCE: BaFCl:Eu²⁺*)

ZHAO HUI, WANG YONGSHENG, XU ZHENG, TANG HUIJUN, XU XURONG

Institute of Optoelectronic Technology, Northern Jiaotong University, Beijing 100044, China

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Transient acceleration process of electrons in ZnS-type thin film electroluminescence devices

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the "fields" in the manuscript are unacceptable! it's a bit better. O.K.?

薄膜电致发光器件中电子输运的瞬态过程*

赵 辉 王永生 徐 征 徐叙琰

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半 导 体 光 电

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无机薄膜电致发光研究进展^{①②}

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ZnS:Mn²⁺ 薄膜电致发光器件中电子散射过程的研究

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高场下界面势垒对双层有机器件复合发光的影响*

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以高场作用下载流子对三角势垒的 Fowler-Nordheim 隧穿理论为基础, 建立了双层有机电致发光器件中载流子的输运和复合发光模型. 计算并讨论了所加电压与界面势垒对器件的复合电流及其复合效率的影响. 该理论模型很好地解释了实验现象, 并进一步证实了电场对复合区域的调制作用.

薄膜场致发光显示的研究进展*

《物理学报》
28卷(1999年)
2期

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CdTe/CdZnTe 多量子阱激子复合动力学性质的研究*

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等

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半导体光电
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蒙特卡洛法模拟半导体高场输运过程^{①②}

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ZnS:Mn 薄膜电致发光器件中的电子能量*

赵辉, 王永生, 徐征, 杨盛谊, 徐叙琰

此为试读, 需要完整PDF请访问: 北方交通大学光电子技术研究所, 北京 100044